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Vishay Siliconix

Automotive N-Channel 40 V (D-S) 175 °C MOSFET

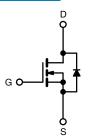


PRODUCT SUMMARY				
V _{DS} (V)	40			
$R_{DS(on)}$ (Ω) at $V_{GS} = 10 \text{ V}$	0.0051			
I _D (A)	114			
Configuration	Single			
Package	PowerPAK SO-8L			

FEATURES

- TrenchFET® Gen IV power MOSFET
- AEC-Q101 qualified
- 100 % Rq and UIS tested
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912





N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)						
PARAMETER		SYMBOL	LIMIT	UNIT		
Drain-source voltage		V_{DS}	40	V		
Gate-source voltage		V_{GS}	± 20	V		
Continuous drain current	T _C = 25 °C	1	114			
	T _C = 125 °C	I _D	66			
Continuous source current (diode conduction)	Is	123	А			
Pulsed drain current ^a	I _{DM}	189				
Single pulse avalanche current	L = 0.1 mH	I _{AS}	18.5			
Single pulse avalanche energy	L = 0.1 IIIII	E _{AS}	17.1	mJ		
Maximum power dissipation ^a	T _C = 25 °C	D	136	W		
	T _C = 125 °C	P_{D}	45	VV		
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +175	°C		
Soldering recommendations (peak temperature)		260				

THERMAL RESISTANCE RATINGS						
PARAMETER		SYMBOL	LIMIT	UNIT		
Junction-to-ambient	PCB mount b	R_{thJA}	42	°C/W		
Junction-to-case (drain)		R_{thJC}	1.1	C/VV		

Notes

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %
- b. When mounted on 1" square PCB (FR4 material)
- c. See solder profile (www.vishay.com/doc?73257). The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection



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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static						•		
Drain-source breakdown voltage	V _{DS}	V _{GS} = 0, I _D = 250 μA		40	-	-	V	
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$		3.0	3.5	V	
Gate-source leakage	I _{GSS}	V _{DS} =	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$		-	± 100	nA	
Zero gate voltage drain current		$V_{GS} = 0 V$	V _{DS} = 40 V	-	-	1		
	I _{DSS}	V _{GS} = 0 V	V _{DS} = 40 V, T _J = 125 °C	-	-	50	μA	
		$V_{GS} = 0 V$	V _{DS} = 40 V, T _J = 175 °C	-	-	250		
On-state drain current a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 V$	30	-	-	Α	
		V _{GS} = 10 V	I _D = 15 A	-	0.004	0.0051		
Drain-source on-state resistance a	R _{DS(on)}	V _{GS} = 10 V	I _D = 15 A, T _J = 125 °C	-	-	0.0084	Ω	
		V _{GS} = 10 V	I _D = 15 A, T _J = 175 °C	-	-	0.0103		
Forward transconductance b	9 _{fs}	V _{DS}	= 15 V, I _D = 10 A	-	45	-	S	
Dynamic ^b								
Input capacitance	C _{iss}		V _{DS} = 25 V, f = 1 MHz	-	1037	1452	pF	
Output capacitance	C _{oss}	$V_{GS} = 0 V$		-	401	562		
Reverse transfer capacitance	C _{rss}			-	51	72		
Total gate charge ^c	Qg			-	18	27		
Gate-source charge c	Q_{gs}	$V_{GS} = 10 \text{ V}$	$V_{DS} = 20 \text{ V}, I_D = 15 \text{ A}$	-	6	-	nC	
Gate-drain charge c	Q_{gd}			-	4	-		
Gate resistance	Rg	f = 1 MHz		3.4	6.8	10.2	Ω	
Turn-on delay time ^c	t _{d(on)}			-	11	17		
Rise time ^c	t _r	V _{DD} =	V_{DD} = 20 V, R_L = 1.33 Ω $I_D \cong$ 15 A, V_{GEN} = 10 V, R_g = 1 Ω		4	8	- ns	
Turn-off delay time ^c	t _{d(off)}				18	27		
Fall time ^c	t _f			-	6	9		
Source-Drain Diode Ratings and Chara	acteristics ^b							
Pulsed current ^a	I _{SM}			-	-	168	Α	
Forward voltage	V _{SD}	I _F = 15 A, V _{GS} = 0 V		-	-	1.1	V	
Body diode reverse recovery time	t _{rr}	I _F = 6 A, di/dt = 100 A/μs		-	24	48	ns	
Body diode reverse recovery charge	Q _{rr}			-	12	24	nC	
Reverse recovery fall time	t _a			-	11	-		
Reverse recovery rise time	t _b			-	13	-	ns	
Body diode peak reverse recovery current	I _{RM(REC)}			-	0.9	-	А	

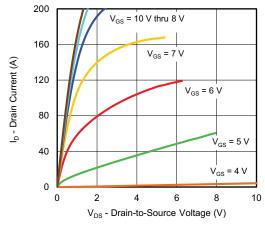
Notes

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%$
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

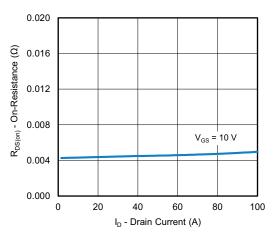
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



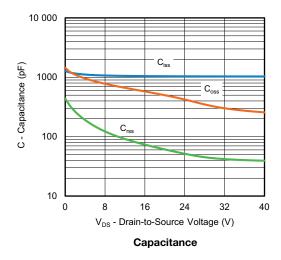
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

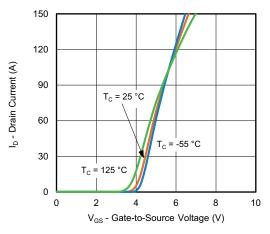


Output Characteristics

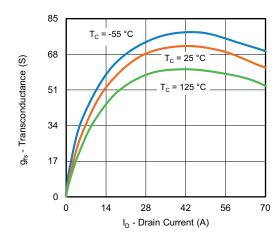


On-Resistance vs. Drain Current

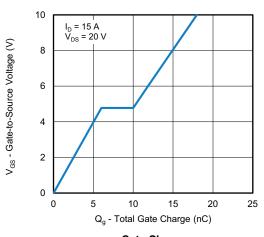




Transfer Characteristics



Transconductance

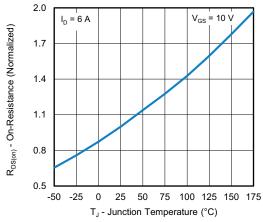


T_J = 150 °C

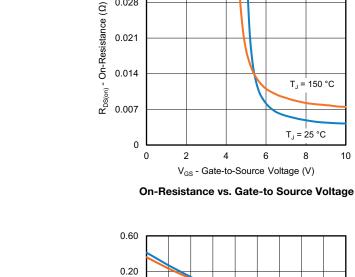
T_J = 25 °C



TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



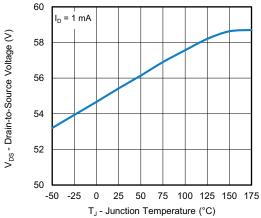
On-Resistance vs. Junction Temperature



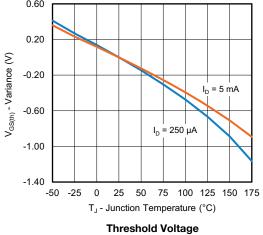
0.035

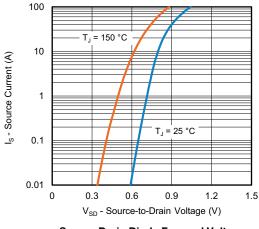
0.028

0.021



Drain Source Breakdown vs. Junction Temperature





Source Drain Diode Forward Voltage

1000 100 I_D - Drain Current (A) 10 100 µs 1 ms Limited by R_{DS(on)} 10 ms 100 ms, 1 s, **BVDSS** limited 10 s, DC 0.1 single pulse 0.01 0.01 V_{DS} - Drain-to-Source Voltage (V)

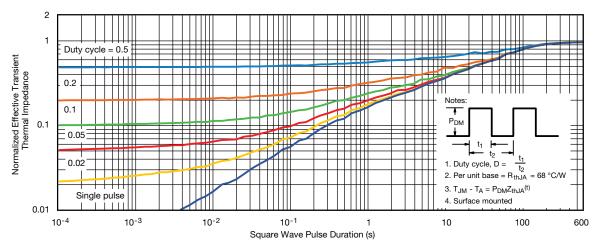
Safe Operating Area

Note

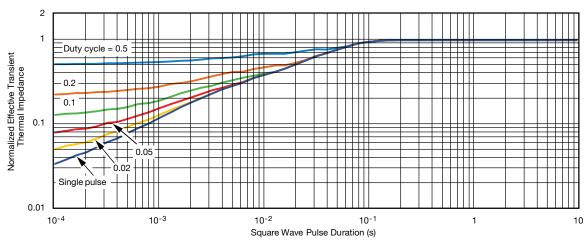
a. V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified



TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

Note

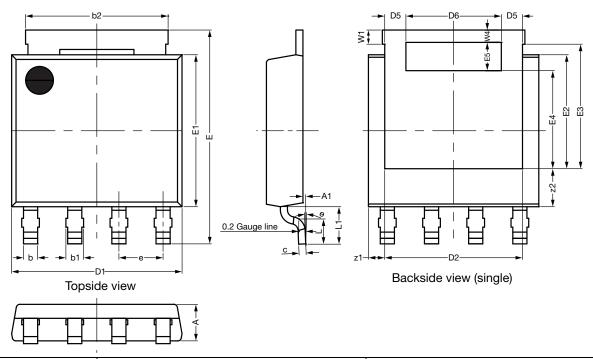
- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?77129.



PowerPAK® SO-8L (PPKSO8LWLA) Case Outline 3



DIM.	MILLIMETERS			INCHES			
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
Α	1.00	1.05	1.10	0.039	0.041	0.043	
A1	0.00		0.127	0.000		0.005	
b	0.33	0.41	0.49	0.013	0.016	0.019	
b1	0.43	0.51	0.59	0.017	0.020	0.023	
b2	4.00	4.10	4.20	0.157	0.161	0.165	
С	0.15	0.20	0.25	0.006	0.008	0.010	
D1	4.80	4.90	5.00	0.189	0.193	0.197	
D2	3.86	3.96	4.06	0.152	0.156	0.160	
D5	0.51	0.61	0.71	0.020	0.024	0.028	
D6	2.64	2.74	2.84	0.104	0.108	0.112	
е		1.27 BSC		0.050 BSC			
E	6.05	6.15	6.25	0.238	0.242	0.246	
E1	4.27	4.37	4.47	0.168	0.172	0.176	
E2	3.18	3.28	3.38	0.125	0.129	0.133	
E3	3.48	3.58	3.68	0.137	0.141	0.145	
E4	2.72	2.82	2.92	0.107	0.111	0.115	
E5	0.71	0.81	0.91	0.028	0.032	0.036	
L	0.62	0.72	0.82	0.024	0.028	0.032	
L1	0.92	1.07	1.22	0.036	0.042	0.048	
W1	0.31	0.41	0.51	0.012	0.016	0.020	
W4	0.31	0.36	0.41	0.012	0.014	0.016	
z1	0.37	0.47	0.57	0.015	0.019	0.022	
z2	0.99	1.09	1.19	0.039	0.043	0.047	
θ	0°		5°	0°		5°	

ECN: C22-1223-Rev. C, 19-Dec-2022

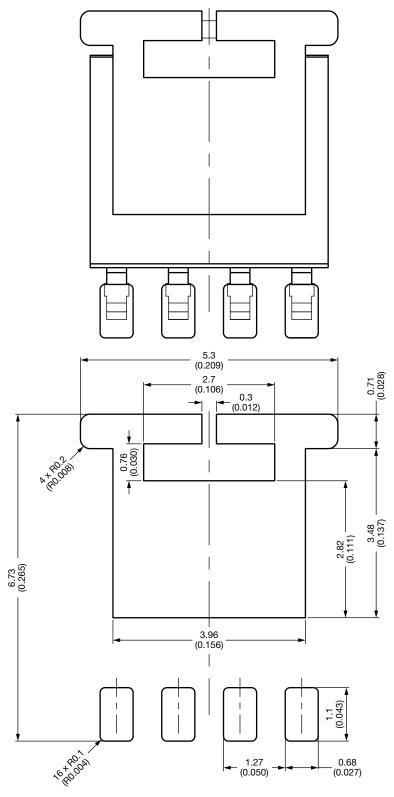
DWG: 6067 **Note**

Millimeter will govern

Revison: 19-Dec-2022 1 Document Number: 76666



Recommended Land Pattern PowerPAK® SO-8L Single Short Ear



Dimensions in Millimeters (Inches)



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